

# Tatsuya Usuki

## List of Publications by Year in descending order

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92  
papers

2,182  
citations

218677

26  
h-index

233421

45  
g-index

93  
all docs

93  
docs citations

93  
times ranked

1735  
citing authors

#	ARTICLE	IF	CITATIONS
1	50-Gb/s ring-resonator-based silicon modulator. <i>Optics Express</i> , 2013, 21, 11869.	3.4	165
2	Numerical analysis of ballistic-electron transport in magnetic fields by using a quantum point contact and a quantum wire. <i>Physical Review B</i> , 1995, 52, 8244-8255.	3.2	157
3	Single-Photon Generation in the 1.55- $\mu\text{m}$ Optical-Fiber Band from an InAs/InP Quantum Dot. <i>Japanese Journal of Applied Physics</i> , 2005, 44, L620-L622.	1.5	120
4	First Demonstration of Athermal Silicon Optical Interposers With Quantum Dot Lasers Operating up to 125 $^{\circ}\text{C}$ . <i>Journal of Lightwave Technology</i> , 2015, 33, 1223-1229.	4.6	106
5	An optical horn structure for single-photon source using quantum dots at telecommunication wavelength. <i>Journal of Applied Physics</i> , 2007, 101, 081720.	2.5	93
6	First demonstration of high density optical interconnects integrated with lasers, optical modulators, and photodetectors on single silicon substrate. <i>Optics Express</i> , 2011, 19, B159.	3.4	90
7	Microstructure and electrical properties of Sn nanocrystals in thin, thermally grown SiO <sub>2</sub> layers formed via low energy ion implantation. <i>Journal of Applied Physics</i> , 1998, 84, 1316-1320.	2.5	72
8	Non-classical Photon Emission from a Single InAs/InP Quantum Dot in the 1.3- $\mu\text{m}$ Optical-Fiber Band. <i>Japanese Journal of Applied Physics</i> , 2004, 43, L993-L995.	1.5	71
9	Charge susceptibility of the one-dimensional Hubbard model. <i>Physics Letters, Section A: General, Atomic and Solid State Physics</i> , 1989, 135, 476-480.	2.1	67
10	125-Gb/s operation with 0.29-V $\mu\text{m}^2$ V <sub>ij</sub> EL using silicon Mach-Zehnder modulator based-on forward-biased pin diode. <i>Optics Express</i> , 2012, 20, 2911.	3.4	62
11	Transmission Experiment of Quantum Keys over 50 km Using High-Performance Quantum-Dot Single-Photon Source at 1.5 $\mu\text{m}$ Wavelength. <i>Applied Physics Express</i> , 2010, 3, 092802.	2.4	58
12	Thermodynamic Quantities of the One-Dimensional Hubbard Model at Finite Temperatures. <i>Journal of the Physical Society of Japan</i> , 1990, 59, 1357-1365.	1.6	57
13	Thermodynamic properties of the one-dimensional Hubbard model. <i>Physics Letters, Section A: General, Atomic and Solid State Physics</i> , 1989, 137, 287-290.	2.1	54
14	Site-controlled photoluminescence at telecommunication wavelength from InAs/InP quantum dots. <i>Applied Physics Letters</i> , 2005, 86, 113118.	3.3	54
15	Demonstration of 125-Gbps optical interconnects integrated with lasers, optical splitters, optical modulators and photodetectors on a single silicon substrate. <i>Optics Express</i> , 2012, 20, B256.	3.4	53
16	Observation of Exciton Transition in 1.3-1.55 $\mu\text{m}$ Band from Single InAs/InP Quantum Dots in Mesa Structure. <i>Japanese Journal of Applied Physics</i> , 2004, 43, L349-L351.	1.5	47
17	Observation of electrostatically released DNA from gold electrodes with controlled threshold voltages. <i>Journal of Chemical Physics</i> , 2004, 120, 5501-5504.	3.0	44
18	Compact PIN-Diode-Based Silicon Modulator Using Side-Wall-Grating Waveguide. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2013, 19, 74-84.	2.9	43

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19	Ultralow-Power (1.59 mW/Gbps), 56-Gbps PAM4 Operation of Si Photonic Transmitter Integrating Segmented PIN Mach-Zehnder Modulator and 28-nm CMOS Driver. <i>Journal of Lightwave Technology</i> , 2018, 36, 1275-1280.	4.6	41
20	Polarization-dependent shift in excitonic Zeeman splitting of self-assembled $\text{In}_{0.75}\text{Al}_{0.25}\text{As}/\text{Al}_{0.3}\text{Ga}_{0.7}\text{As}$ quantum dots. <i>Physical Review B</i> , 2005, 71, .	3.2	40
21	High-density and wide-bandwidth optical interconnects with silicon optical interposers [Invited]. <i>Photonics Research</i> , 2014, 2, A1.	7.0	40
22	Theoretical study of Landau-Zener tunneling at the $M+N$ level crossing. <i>Physical Review B</i> , 1997, 56, 13360-13366.	3.2	39
23	Laterally coupled self-assembled InAs quantum dots embedded in resonant tunnel diode with multigate electrodes. <i>Applied Physics Letters</i> , 2008, 92, .	3.3	35
24	Time-Resolved Study of Carrier Transfer among InAs/GaAs Multi-Coupled Quantum Dots. <i>Japanese Journal of Applied Physics</i> , 1995, 34, L1439.	1.5	34
25	Time-Resolved Study of Carrier Transfer among InAs/GaAs Multi-Coupled Quantum Dots. <i>Japanese Journal of Applied Physics</i> , 1995, 34, L1439-L1441.	1.5	34
26	Numerical analysis of electron-wave detection by a wedge-shaped point contact. <i>Physical Review B</i> , 1994, 50, 7615-7625.	3.2	29
27	A 1 V Peak-to-Peak Driven 10-Gbps Slow-Light Silicon Mach-Zehnder Modulator Using Cascaded Ring Resonators. <i>Applied Physics Express</i> , 2010, 3, 072202.	2.4	28
28	Few-Electron Molecular States and Their Transitions in a Single InAs Quantum Dot Molecule. <i>Physical Review Letters</i> , 2005, 95, 236801.	7.8	25
29	First Demonstration of Electrically Driven 1.55 $\mu\text{m}$ Single-Photon Generator. <i>Japanese Journal of Applied Physics</i> , 2008, 47, 2880-2883.	1.5	25
30	Photon Antibunching Observed from an InAlAs Single Quantum Dot. <i>Japanese Journal of Applied Physics</i> , 2005, 44, L793-L796.	1.5	24
31	Spin Depolarization via Tunneling Effects in Asymmetric Double Quantum Dot Structure. <i>Japanese Journal of Applied Physics</i> , 2004, 43, 2110-2113.	1.5	23
32	High-speed and efficient silicon modulator based on forward-biased pin diodes. <i>Frontiers in Physics</i> , 2014, 2, .	2.1	20
33	$V_{\text{sub th}}$ fluctuation induced by statistical variation of pocket dopant profile. , 0, , .		19
34	Controlling emission wavelength from InAs self-assembled quantum dots on InP (001) during MOCVD. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2005, 26, 81-85.	2.7	19
35	Site-controlled quantum dots fabricated using an atomic-force microscope assisted technique. <i>Nanoscale Research Letters</i> , 2006, 1, 160-166.	5.7	19
36	Thermoelectric Power of the Anderson Model at Low Temperatures. <i>Journal of the Physical Society of Japan</i> , 1987, 56, 1539-1545.	1.6	18

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37	A proposal of new floating-dot memory storing a small number of electrons with relatively long retention time at low voltage operations. <i>Microelectronic Engineering</i> , 1999, 47, 281-283.	2.4	17
38	Exciton dynamics in current-injected single quantum dot at 1.55 $\mu$ m. <i>Applied Physics Letters</i> , 2008, 92, 161104.	3.3	17
39	Cascaded-ring-resonator-loaded Mach-Zehnder modulator for enhanced modulation efficiency in wide optical bandwidth. <i>Optics Express</i> , 2012, 20, 16321.	3.4	15
40	Radiative recombination of excitons in disk-shaped quantum dots. <i>Physical Review B</i> , 2007, 76, 045307.	3.2	14
41	Development of Electrically Driven Single-Quantum-Dot Device at Optical Fiber Bands. <i>Japanese Journal of Applied Physics</i> , 2006, 45, 3621-3624.	1.5	13
42	25-Gb/s broadband silicon modulator with 0.31-V $\cdot$ cm V $\pi$ based on forward-biased PIN diodes embedded with passive equalizer. <i>Optics Express</i> , 2015, 23, 32950.	3.4	13
43	Accurate SPICE Model of Forward-Biased Silicon PIN Mach-Zehnder Modulator for an Energy-Efficient Multilevel Transmitter. <i>Journal of Lightwave Technology</i> , 2018, 36, 1959-1969.	4.6	13
44	Single InAs/InP quantum dot spectroscopy in 1.3 $\mu$ m-1.55 $\mu$ m telecommunication band. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2005, 26, 185-189.	2.7	11
45	Single-photon interferography in InAs/InP quantum dots emitting at 1300nm wavelength. <i>Applied Physics Letters</i> , 2007, 91, 223113.	3.3	10
46	Robust Optical Data Transfer on Silicon Photonic Chip. <i>Journal of Lightwave Technology</i> , 2012, 30, 2933-2940.	4.6	10
47	Coupling between one-dimensional states in a quantum point contact and an electron waveguide. <i>Applied Physics Letters</i> , 1994, 65, 3087-3089.	3.3	9
48	Triggered single-photon emission and cross-correlation properties in InAlAs quantum dot. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2006, 32, 144-147.	2.7	9
49	High-density optical interconnects by using silicon photonics. <i>Proceedings of SPIE</i> , 2014, , .	0.8	8
50	Observation of Overhauser shift in a self-assembled InAlAs quantum dot. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2005, 29, 510-514.	2.7	7
51	Magnetization curve for the heavy fermion compounds CeAl <sub>3</sub> and CeCu <sub>2</sub> Si <sub>2</sub> . <i>Journal of Magnetism and Magnetic Materials</i> , 1988, 76-77, 121-122.	2.3	6
52	Analysis of Landau-Zener tunneling with an Ohmic reservoir and a noise source. <i>Physical Review B</i> , 1998, 57, 7124-7131.	3.2	6
53	Single-photon generation from InAlAs single quantum dot. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2005, 2, 3833-3837.	0.8	6
54	Electric field modulation of exciton recombination in InAs/GaAs quantum dots emitting at 1.3 $\mu$ m. <i>Journal of Applied Physics</i> , 2008, 104, 013504.	2.5	6

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55	Coulomb interaction in asymmetric triple-coupled quantum dots. <i>Semiconductor Science and Technology</i> , 2004, 19, S409-S411.	2.0	5
56	Metal Oxide Semiconductor Field Effect Transistor (MOSFET) Model Based on a Physical High-Field Carrier-Velocity Model. <i>Japanese Journal of Applied Physics</i> , 2004, 43, 77-81.	1.5	5
57	Magnetization Curve for Ce Compounds in the Crystalline Field. <i>Journal of the Physical Society of Japan</i> , 1989, 58, 1427-1432.	1.6	4
58	Scanning tunneling microscope study of capped quantum dots. <i>Applied Physics Letters</i> , 2004, 85, 2355-2357.	3.3	4
59	Decoherence of single photons from an InAs/InP quantum dot emitting at a 1.3 $\mu$ m wavelength. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2009, 6, 944-947.	0.8	4
60	Differential signal transmission in silicon-photonics integrated circuit for high density optical interconnects. , 2011, , .		4
61	First Demonstration of High Density Optical Interconnects Integrated with Lasers, Optical Modulators and Photodetectors on a Single Silicon Substrate. , 2011, , .		4
62	Demonstration of 12.5-Gbps Optical Interconnects Integrated with Lasers, Optical Splitters, Optical Modulators and Photodetectors on a Single Silicon Substrate. , 2012, , .		4
63	Demonstration of 25-Gbps optical data links on silicon optical interposer using FPGA transceiver. , 2014, , .		4
64	Wavelength-routing interconnect "Optical Hub" for parallel computing systems. , 2020, , .		4
65	Theoretical Analysis of Write Errors and Number of Stored Electrons for Ten-Nanoscale Si Floating-Dot Memory. <i>Japanese Journal of Applied Physics</i> , 1998, 37, L709-L711.	1.5	3
66	Slow-Light Silicon Mach-Zehnder Modulator Based-on Cascaded Ring Resonators. , 2010, , .		3
67	High-performance silicon modulator for integrated transceivers fabricated on 300-mm wafer. , 2014, , .		3
68	Silicon-Wire Waveguide Based External Cavity Laser for Milliwatt-Order Output Power and Temperature Control Free Operation with Silicon Ring Modulator. <i>Japanese Journal of Applied Physics</i> , 2012, 51, 082101.	1.5	3
69	Sub-GHz operation of single-photon emitting diode at 1.55 $\mu$ m. <i>Proceedings of SPIE</i> , 2009, , .	0.8	2
70	Hybrid laser with Si ring resonator and SOA for temperature control free operation with ring resonator-based modulator. , 2011, , .		2
71	Ultra-Low-Power (1.59 mW/Gbps), 56-Gbps PAM4 Operation of Si Photonic Transmitter Integrating Segmented PIN Mach-Zehnder Modulator and 28-nm CMOS Driver. , 2017, , .		2
72	High-density Silicon Optical Interposer for Inter-chip Interconnects based on Compact and High Speed Components. , 2013, , .		2

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73	Trade-off between operational speed and error occurrence for single electron circuits on the quantum scale. <i>Microelectronic Engineering</i> , 1999, 47, 269-271.	2.4	1
74	Mechanism of Quantum Dot Formation by Postgrowth Annealing of Wetting Layer. <i>Japanese Journal of Applied Physics</i> , 2006, 45, 3564-3567.	1.5	1
75	Silicon-Wire Waveguide Based External Cavity Laser for Milliwatt-Order Output Power and Temperature Control Free Operation with Silicon Ring Modulator. <i>Japanese Journal of Applied Physics</i> , 2012, 51, 082101.	1.5	1
76	Bit error rate analysis of a silicon optical interposer using its equivalent circuit. <i>IEICE Electronics Express</i> , 2015, 12, 20141084-20141084.	0.8	1
77	Advances in High-Density Inter-Chip Interconnects with Photonic Wiring. <i>IEICE Transactions on Electronics</i> , 2013, E96.C, 958-965.	0.6	1
78	A direct tunneling memory using ultra-thin oxide and deca-nano floating gate structure. <i>Superlattices and Microstructures</i> , 2000, 28, 401-406.	3.1	0
79	Sharp Interfacial Structure of InAs/InP Quantum Dots Grown by a Double-Cap Method: A Cross-Sectional Scanning Tunneling Microscopy Study. <i>AIP Conference Proceedings</i> , 2007, , .	0.4	0
80	Tunneling-Injection Single-Photon Emitter Using Charged Exciton State. <i>Japanese Journal of Applied Physics</i> , 2009, 48, 06FF01.	1.5	0
81	Athermal silicon optical interposers with quantum dot lasers operating from 25 to 125°C. <i>Electronics Letters</i> , 2014, 50, 1377-1378.	1.0	0
82	Athermal silicon optical interposers operating up to 125°C. <i>Proceedings of SPIE</i> , 2015, , .	0.8	0
83	Numerical simulation of waveguide light scattering for Si photonics. , 2017, , .		0
84	Numerical Designing of Optical Waveguide by Curvilinear Coordinates. , 2019, , .		0
85	Advantage of a Quasi-Nonvolatile Memory with Ultra Thin Oxide. , 2001, , .		0
86	Development of Electrically Driven Single-Photon Emitter at Optical Fiber Bands. , 2005, , .		0
87	Single-photon generator for telecom applications. , 2006, , .		0
88	First Demonstration of Electrically Driven 1.55 $\mu$ m Single-Photon Generator. , 2007, , .		0
89	Fully Integrated Silicon Optical Interposers with High Bandwidth Density. , 2014, , .		0
90	InAs/GaAs Multi-Coupled Quantum Dots Structure Enabling High-Intensity, Near-1.3 $\mu$ m Emission due to Cascade Carrier Tunneling. , 1995, , .		0

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91	Studies of Semiconductor Quantum Dots for Quantum Information Processing. , 2008, , 267-296.		0
92	Error-Free Operation for Fully Connected Wavelength-Routing Interconnect among 8 FPGAs with 2.8-Tbit/s Total Bandwidth. , 2021, , .		0